

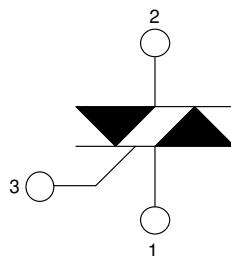
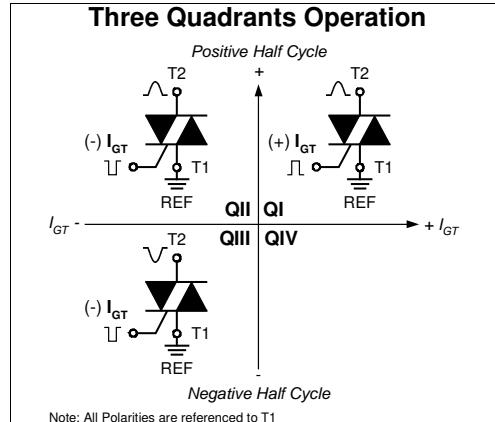
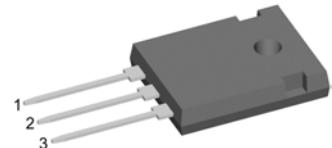
# Thyristor

$V_{RRM}$  = 1600 V  
 $I_{TAV}$  = 40 A  
 $V_T$  = 1,34 V

Three Quadrants operation: QI - QIII  
1~ Triac

## Part number

**CMA80MT1600NHB**



Backside: Terminal 2

## Features / Advantages:

- Triac for line frequency
- Three Quadrants Operation - QI - QIII
- Planar passivated chip
- Long-term stability of blocking currents and voltages

## Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

## Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

## Disclaimer Notice

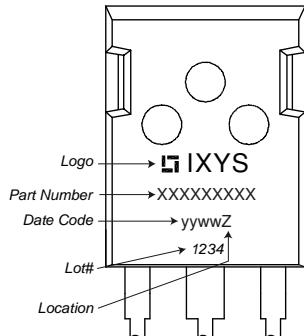
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**Rectifier**
**Ratings**

| Symbol         | Definition   | Conditions   | min.  | typ. | max.                         | Unit          |
|----------------|--|--|---|------|------------------------------|---------------|
| $V_{RSM/DSM}$  | max. non-repetitive reverse/forward blocking voltage | $T_{VJ} = 25^\circ C$  |   |      | 1700                         | V             |
| $V_{RRM/DRM}$  | max. repetitive reverse/forward blocking voltage     | $T_{VJ} = 25^\circ C$  |   |      | 1600                         | V             |
| $I_{R/D}$      | reverse current, drain current                       | $V_{R/D} = 1600 V$<br>$V_{R/D} = 1600 V$   | $T_{VJ} = 25^\circ C$<br>$T_{VJ} = 125^\circ C$                               |      | 10<br>2                      | $\mu A$<br>mA |
| $V_T$          | forward voltage drop                                 | $I_T = 40 A$<br>$I_T = 80 A$<br>$I_T = 40 A$<br>$I_T = 80 A$   | $T_{VJ} = 25^\circ C$<br>$T_{VJ} = 125^\circ C$                               |      | 1,36<br>1,70<br>1,34<br>1,78 | V<br>V        |
| $I_{TAV}$      | average forward current                              | $T_C = 115^\circ C$  | $T_{VJ} = 150^\circ C$  |      | 40                           | A             |
| $I_{RMS}$      | RMS forward current per phase                        | 180° sine  |   |      | 88                           | A             |
| $V_{TO}$       | threshold voltage                                    | $r_T$<br>slope resistance } for power loss calculation only  | $T_{VJ} = 150^\circ C$  |      | 0,89                         | V             |
|                | slope resistance                                     |  |   |      | 11,3                         | $m\Omega$     |
| $R_{thJC}$     | thermal resistance junction to case                  |  |   |      | 0,4                          | K/W           |
| $R_{thCH}$     | thermal resistance case to heatsink                  |  |   |      | 0,25                         | K/W           |
| $P_{tot}$      | total power dissipation                              |  | $T_C = 25^\circ C$  |      | 310                          | W             |
| $I_{TSM}$      | max. forward surge current                           | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$<br>$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$<br>$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$<br>$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ | $T_{VJ} = 45^\circ C$<br>$V_R = 0 V$<br>$T_{VJ} = 150^\circ C$<br>$V_R = 0 V$ |      | 380<br>410<br>325<br>350     | A             |
| $I^2t$         | value for fusing                                     | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$<br>$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$<br>$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$<br>$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ | $T_{VJ} = 45^\circ C$<br>$V_R = 0 V$<br>$T_{VJ} = 150^\circ C$<br>$V_R = 0 V$ |      | 720<br>700<br>530<br>510     | $A^2s$        |
| $C_J$          | junction capacitance                                 | $V_R = 400 V$ $f = 1 \text{ MHz}$  | $T_{VJ} = 25^\circ C$   |      | 14                           | pF            |
| $P_{GM}$       | max. gate power dissipation                          | $t_p = 30 \mu s$<br>$t_p = 300 \mu s$  | $T_C = 150^\circ C$   |      | 10<br>5<br>0,5               | W<br>W<br>W   |
| $P_{GAV}$      | average gate power dissipation                       |  |   |      |                              |               |
| $(di/dt)_{cr}$ | critical rate of rise of current                     | $T_{VJ} = 125^\circ C; f = 50 \text{ Hz}$ repetitive, $I_T = 90 A$<br>$t_p = 200 \mu s; di_G/dt = 0,2 A/\mu s;$<br>$I_G = 0,2 A; V_D = \frac{2}{3} V_{DRM}$ non-repet., $I_T = 40 A$                               |   |      | 150                          | $A/\mu s$     |
| $(dv/dt)_{cr}$ | critical rate of rise of voltage                     | $V_D = \frac{2}{3} V_{DRM}$<br>$R_{GK} = \infty$ ; method 1 (linear voltage rise)  | $T_{VJ} = 125^\circ C$  |      | 500                          | $V/\mu s$     |
| $V_{GT}$       | gate trigger voltage                                 | $V_D = 6 V$  | $T_{VJ} = 25^\circ C$<br>$T_{VJ} = -40^\circ C$                               |      | 1,7<br>1,9                   | V             |
| $I_{GT}$       | gate trigger current                                 | $V_D = 6 V$  | $T_{VJ} = 25^\circ C$<br>$T_{VJ} = -40^\circ C$                               |      | $\pm 70$<br>$\pm 90$         | mA            |
| $V_{GD}$       | gate non-trigger voltage                             | $V_D = \frac{2}{3} V_{DRM}$  | $T_{VJ} = 125^\circ C$  |      | 0,2                          | V             |
| $I_{GD}$       | gate non-trigger current                             |  |   |      | $\pm 1$                      | mA            |
| $I_L$          | latching current                                     | $t_p = 10 \mu s$<br>$I_G = 0,2 A; di_G/dt = 0,2 A/\mu s$   | $T_{VJ} = 25^\circ C$   |      | 100                          | mA            |
| $I_H$          | holding current                                      | $V_D = 6 V$ $R_{GK} = \infty$  | $T_{VJ} = 25^\circ C$   |      | 70                           | mA            |
| $t_{gd}$       | gate controlled delay time                           | $V_D = \frac{1}{2} V_{DRM}$<br>$I_G = 0,5 A; di_G/dt = 0,5 A/\mu s$  | $T_{VJ} = 25^\circ C$   |      | 2                            | $\mu s$       |
| $t_q$          | turn-off time  | $V_R = 100 V; I_T = 40 A; V_D = \frac{2}{3} V_{DRM}$ $T_{VJ} = 125^\circ C$<br>$di/dt = 10 A/\mu s; dv/dt = 20 V/\mu s; t_p = 200 \mu s$   |   | 150  |                              | $\mu s$       |

**Package TO-247**

| Symbol        | Definition                   | Conditions   | min. | typ. | max. | Unit |
|---------------|------------------------------|--------------|------|------|------|------|
| $I_{RMS}$     | RMS current                  | per terminal |      |      | 70   | A    |
| $T_{VJ}$      | virtual junction temperature |              | -40  |      | 150  | °C   |
| $T_{op}$      | operation temperature        |              | -40  |      | 125  | °C   |
| $T_{stg}$     | storage temperature          |              | -40  |      | 150  | °C   |
| <b>Weight</b> |                              |              |      | 6    |      | g    |
| $M_D$         | mounting torque              |              | 0,8  |      | 1,2  | Nm   |
| $F_c$         | mounting force with clip     |              | 20   |      | 120  | N    |

**Product Marking**

**Part description**

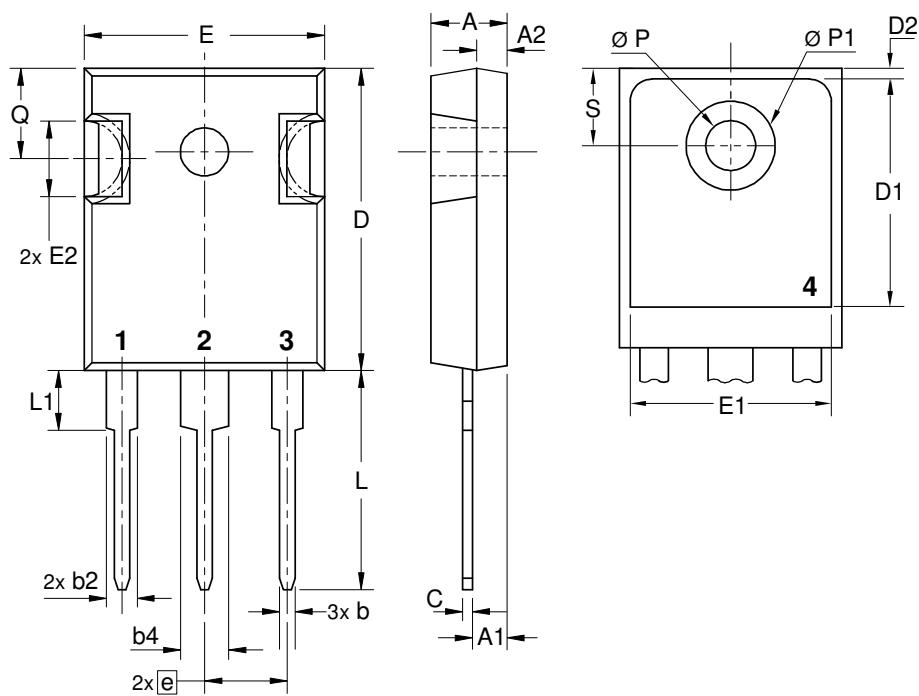
C = Thyristor (SCR)  
 M = Thyristor  
 A = (up to 1800V)  
 80 = Current Rating [A]  
 MT = 1~ Triac  
 1600 = Reverse Voltage [V]  
 N = Three Quadrants operation: QI - QIII  
 HB = TO-247AD (3)

| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | CMA80MT1600NHB  | CMA80MT1600NHB     | Tube          | 30       | 522868   |

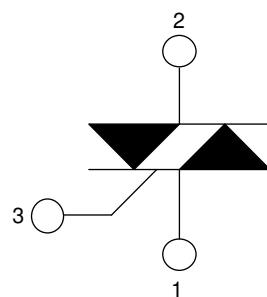
| Similar Part   | Package    | Voltage class |
|----------------|------------|---------------|
| CMA80MT1600NHR | ISO247 (3) | 1600          |

**Equivalent Circuits for Simulation**
\* on die level
 $T_{VJ} = 150^\circ\text{C}$ 

|              |                    |        |
|--------------|--------------------|--------|
|              | <b>Thyristor</b>   |        |
| $V_0$        |                    |        |
| $V_{0\ max}$ | threshold voltage  | 0,89 V |
| $R_{0\ max}$ | slope resistance * | 8,8 mΩ |

**Outlines TO-247**


| Sym. | Inches<br>min.<br>max. | Millimeter<br>min.<br>max. |
|------|------------------------|----------------------------|
| A    | 0.185 0.209            | 4.70 5.30                  |
| A1   | 0.087 0.102            | 2.21 2.59                  |
| A2   | 0.059 0.098            | 1.50 2.49                  |
| D    | 0.819 0.845            | 20.79 21.45                |
| E    | 0.610 0.640            | 15.48 16.24                |
| E2   | 0.170 0.216            | 4.31 5.48                  |
| e    | 0.215 BSC              | 5.46 BSC                   |
| L    | 0.780 0.800            | 19.80 20.30                |
| L1   | - 0.177                | - 4.49                     |
| Ø P  | 0.140 0.144            | 3.55 3.65                  |
| Q    | 0.212 0.244            | 5.38 6.19                  |
| S    | 0.242 BSC              | 6.14 BSC                   |
| b    | 0.039 0.055            | 0.99 1.40                  |
| b2   | 0.065 0.094            | 1.65 2.39                  |
| b4   | 0.102 0.135            | 2.59 3.43                  |
| c    | 0.015 0.035            | 0.38 0.89                  |
| D1   | 0.515 -                | 13.07 -                    |
| D2   | 0.020 0.053            | 0.51 1.35                  |
| E1   | 0.530 -                | 13.45 -                    |
| Ø P1 | - 0.29                 | - 7.39                     |



## Thyristor

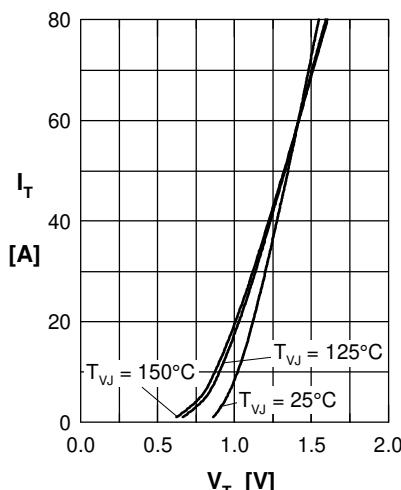


Fig. 1 Forward characteristics

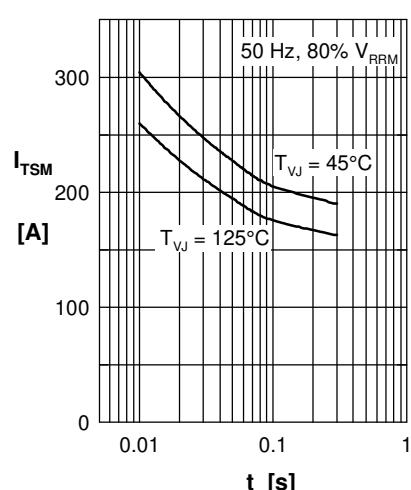


Fig. 2 Surge overload current  
 $I_{TSM}$ : crest value,  $t$ : duration

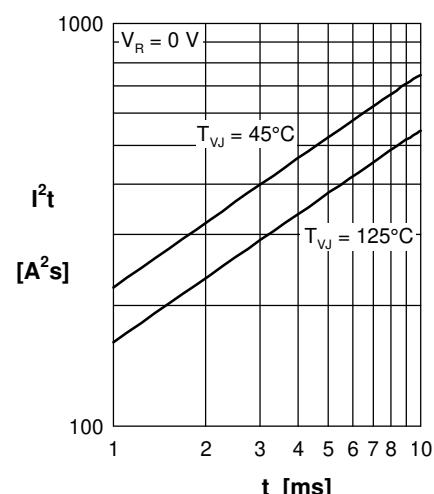


Fig. 3  $I^2t$  versus time (1-10 s)

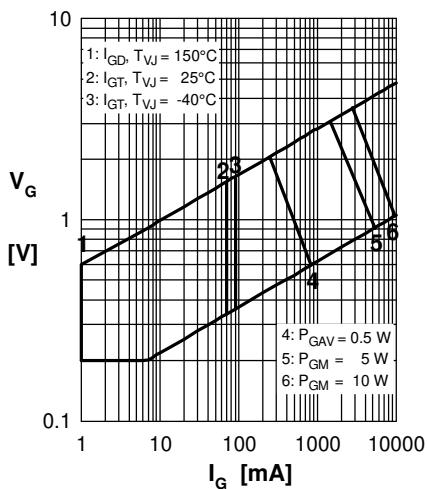


Fig. 4 Gate voltage & gate current

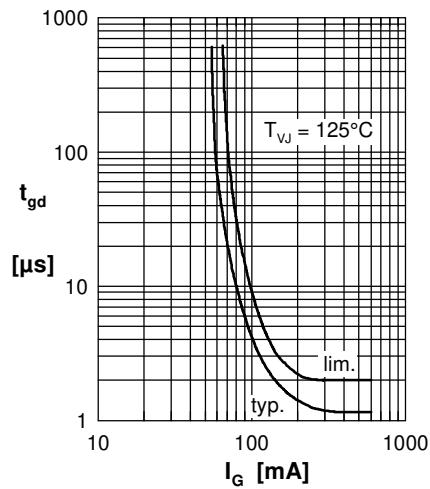


Fig. 5 Gate controlled delay time  $t_{gd}$

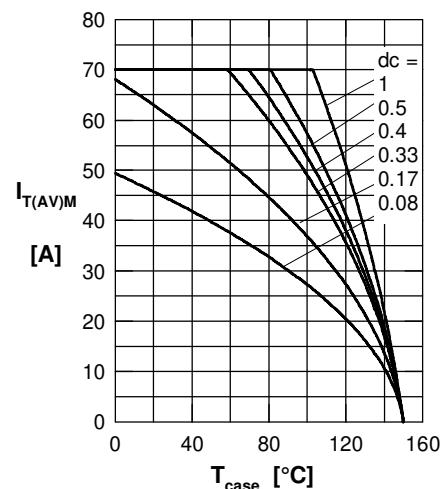


Fig. 6 Max. forward current at case temperature

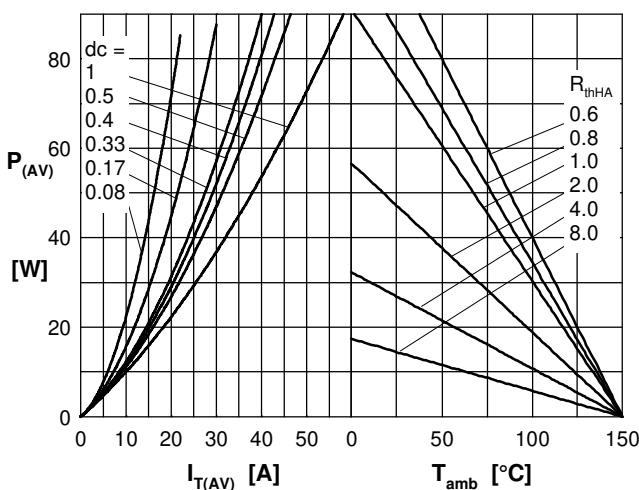


Fig. 7a Power dissipation versus direct output current  
Fig. 7b and ambient temperature

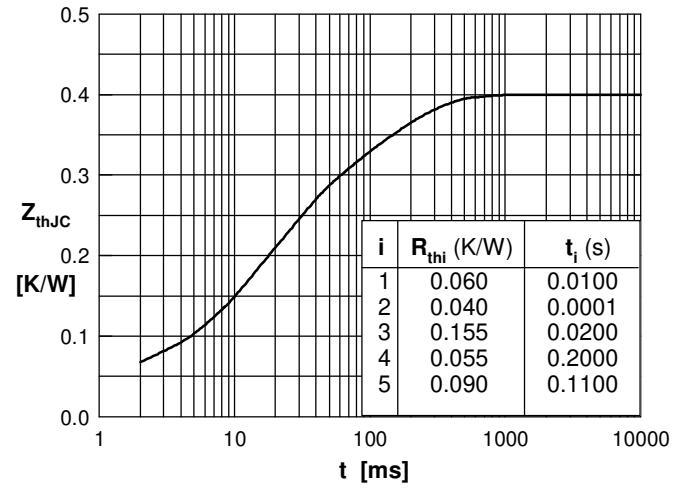


Fig. 7b Transient thermal impedance junction to case